

MDL-NS-633/1-100mW



NANOSECOND PULSED RED DIODE LASER AT 633nm

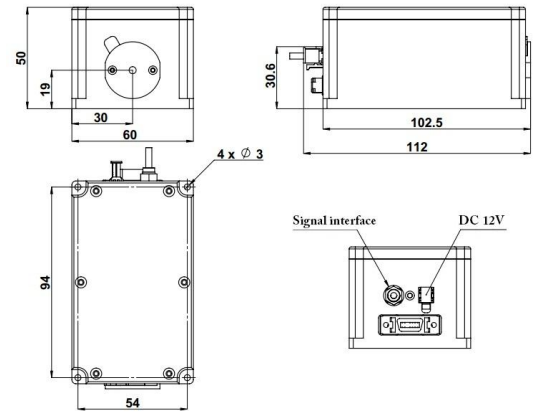
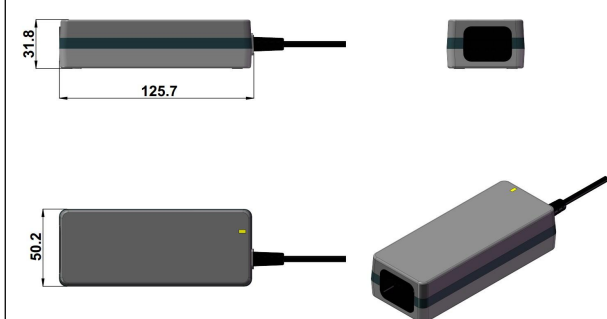
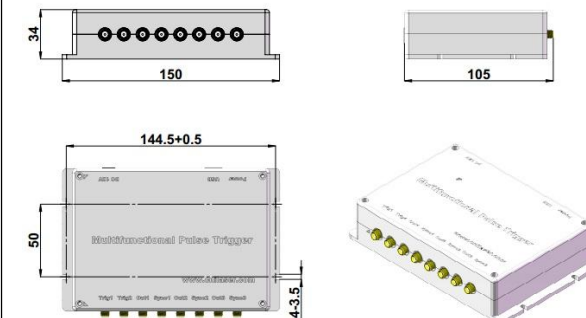
This series laser products with excellent material removal rate, are widely used in microelectronics, material processing, solar energy and medical equipment manufacturing, etc.



SPECIFICATIONS

Central wavelength (nm)	633±3
Operating mode	Pulsed
Peak power (mW) ¹	1-100
Power stability (rms, 4 hours ± 3°C)	<2%, <1%, <0.5%
Pulse width (FWHM)	10ns-10ms
Transverse mode	Near TEM ₀₀
M ²	<1.2
Beam diameter at the aperture (1/e ² ,mm)	~1.2
Beam divergence, full angle (mrad)	<1.0
Polarization ratio	>50:1, (>100:1 optional) Horizontal±5 degree (Vertical optional)
Rep. rate ²	DC-20MHz
Rise Time (ns)	<4
Fall Time (ns)	<3
Modulation Depth (extinction ratio)	>1000000:1
Warm-up time (minutes)	<5
Cooled method	Conduction
Beam height from base plate (mm)	19
Operating temperature (°C)	10-35
Operating voltage (VDC)	12V/3.34A
Expected lifetime (hours)	>10000



LASER HEAD (DRIVER Integrated) ³	POWER SUPPLY (100-240VAC) optional	MULTIFUNCTIONAL PULSE TRIGGER optional
 <p>112 (L) × 60 (W) × 50 (H) mm³, 0.5kg</p>	 <p>125.7 (L) × 50.2 (W) × 31.8 (H) mm³, 0.3kg</p>	 <p>150 (L) × 105 (W) × 34 (H) mm³, 0.5kg</p>

1 Any power level can be selected in this range.

2 Both internal and external triggers are acceptable. The internal trigger supports a frequency range of DC-20MHz.

3 RS232 control optional, output power adjustable 10-100% by software.